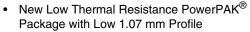


N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)	Q _g (Typ.)			
30	0.0042 at V _{GS} = 10 V	25	27			
	0.0057 at V _{GS} = 4.5 V	22	21			

FEATURES

- · Halogen-free available
- TrenchFET® Power MOSFET

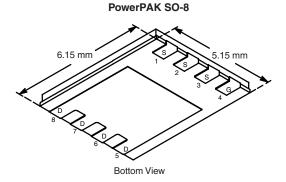


- Low Gate Charge
- 100 % R_g Tested

APPLICATIONS

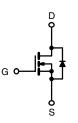
· Synchronous Rectifier





Ordering Information: Si7892BDP-T1-E3 (Lead (Pb)-free)

Si7892BDP-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T	$A = 25 ^{\circ}C$, unles	ss otherwise n	oted		
Parameter	Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	30		V
Gate-Source Voltage		V _{GS}	± 20		V
Continuous Drain Current (T, = 150°C) ^a	T _A = 25 °C	I _D	25	15	
Continuous Diam Current (1) = 150 C)	T _A = 70 °C		20	12	
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	60		Α
Continuous Source Current (Diode Conduction) ^a		I _S	4.1	1.5	
Avalanche Current L = 0.1 mH		I _{AS}	40		
Single Pulse Avalanche Energy		E _{AS}	80		mJ
Maximum Dawar Dissipations	T _A = 25 °C	P _D	5	1.8	W
Maximum Power Dissipation ^a	T _A = 70 °C	, р	3.2	1.1	VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature)b,		260			

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	t ≤ 10 s	R _{thJA}	20	25	°C/W	
Maximum Junction-to-Ambient	Steady State	' 'tnJA	53	70		
Maximum Junction-to-Case (Drain)	Steady State	R_{thJC}	2.1	3.2		

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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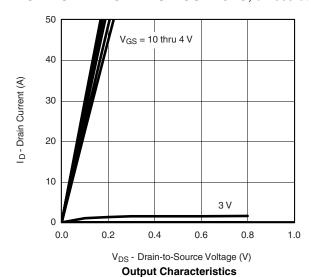
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static				•		•		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0		3.0	V		
V _{DS} Temperature Coefficient	$\Delta V_{DS/Tj}$	I _D = 250 μA		28		mV/°C		
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)/Tj}$	10 = 200 μΑ		- 6.5				
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA		
Zero Gate Voltage Drain Current	Inno	V _{DS} = 30 V, V _{GS} = 0 V			1	^		
Zero Gate Voltage Diairi Current	I _{DSS} –	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			5	μΑ		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α		
Duein Course On Chata Basistanas	B	$V_{GS} = 10 \text{ V}, I_D = 25 \text{ A}$	0.0034 0.0		0.0042	0		
Drain-Source On-State Resistance ^a	R _{DS(on)} –	$V_{GS} = 4.5 \text{ V}, I_D = 22 \text{ A}$		0.0047	0.0057	Ω		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, I_D = 25 \text{ A}$		85		S		
Diode Forward Voltage ^a	V _{SD}	$I_S = 4.5 \text{ A}, V_{GS} = 0 \text{ V}$		0.75	1.2	V		
Dynamic ^b								
Input Capacitance	C _{iss}			3775				
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{SS} = 0 \text{ V}, f = 1 \text{ Hz}$		630		pF		
Reverse Transfer Capacitance	C _{rss}			295				
Total Gate Charge	Qg			27	40			
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 25 \text{ A}$		11.4		nC		
Gate-Drain Charge	Q _{gd}			8.1				
Gate Resistance	R _g		0.5	1.2	2.0	Ω		
Turn-On Delay Time	t _{d(on)}			20	30			
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		13	20			
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_G = 6 Ω		62	100	ns		
Fall Time	t _f			20	35	1		
Source-Drain Reverse Recovery	t _{rr}	I _E = 2.9 A, di/dt = 100 A/μs		40	60	1		
Reverse Recovery Charge	Q _{rr}	1 _F = 2.3 A, α//αι = 100 A/μS		40	60	nC		

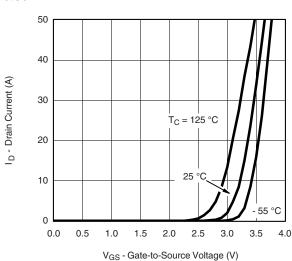
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





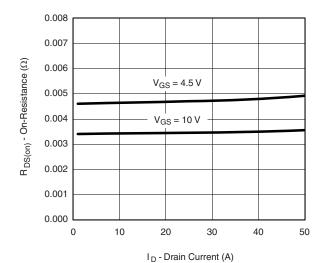
Transfer Characteristics



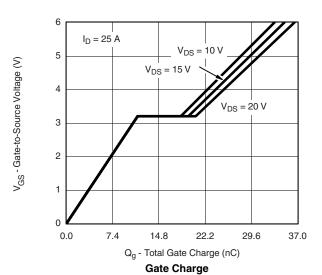


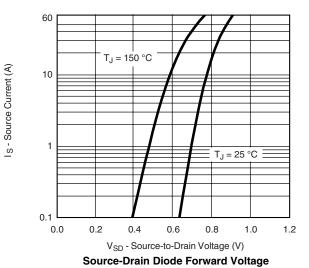


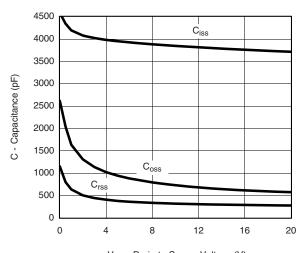
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



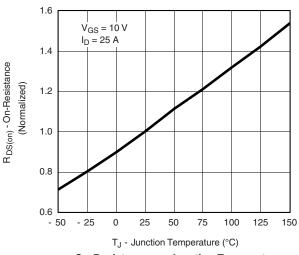
On-Resistance vs. Drain Current



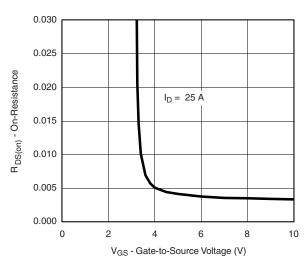




V_{DS} - Drain-to-Source Voltage (V) **Capacitance**



On-Resistance vs. Junction Temperature

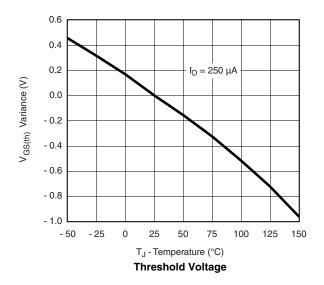


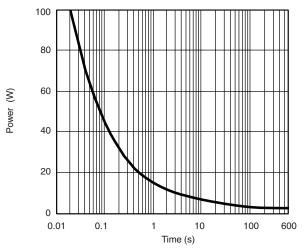
On-Resistance vs. Gate-to-Source Voltage

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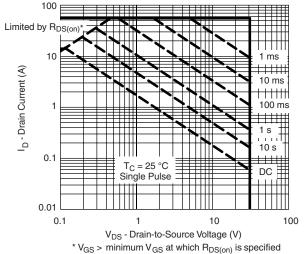
VISHAY

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

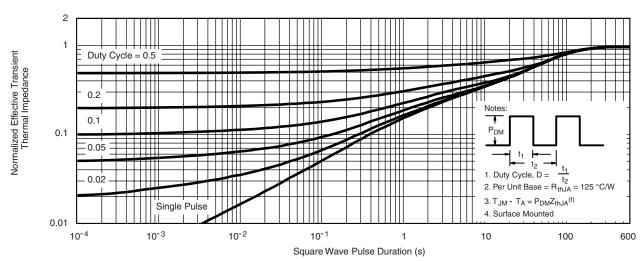




Single Pulse Power



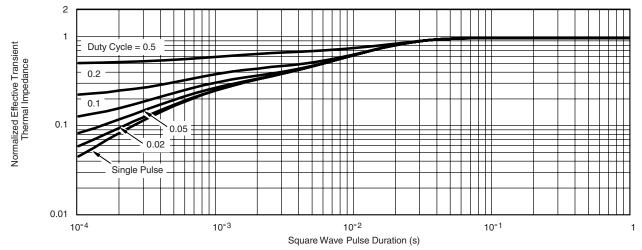
Safe Operating Area, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?73228.

Document Number: 73228 S-80440-Rev. C, 03-Mar-08



DWG: 5881

PowerPAK® SO-8, (Single/Dual)



	3. Dimensions exclusive	of mold flash and cuttin	g burrs.					
		MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
A	0.97	1.04	1.12	0.038	0.041	0.044		
A1		-	0.05	0	-	0.002		
b	0.33	0.41	0.51	0.013	0.016	0.020		
С	0.23	0.28	0.33	0.009	0.011	0.013		
D	5.05	5.15	5.26	0.199	0.203	0.207		
	4.00	4.00	F 00	0.400	0.400	0.407		

Α	0.97	1.04	1.12	0.038	0.041	0.044	
A1		-	0.05	0	-	0.002	
b	0.33	0.41	0.51	0.013	0.016	0.020	
С	0.23	0.28	0.33	0.009	0.011	0.013	
D	5.05	5.15	5.26	0.199	0.203	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.56	3.76	3.91	0.140	0.148	0.154	
D3	1.32	1.50	1.68	0.052	0.059	0.066	
D4		0.57 typ.			0.0225 typ.		
D5		3.98 typ.		0.157 typ.			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	5.79	5.89	5.99	0.228	0.232	0.236	
E2 (for AL product)	3.30	3.48	3.66	0.130	0.137	0.144	
E2 (for other product)	3.48	3.66	3.84	0.137	0.144	0.151	
E3	3.68	3.78	3.91	0.145	0.149	0.154	
E4 (for AL product)		0.58 typ.			0.023 typ.		
E4 (for other product)		0.75 typ.		0.030 typ.			
е		1.27 BSC		0.050 BSC			
K (for AL product)		1.45 typ.		0.057 typ.			
K (for other product)		1.27 typ.		0.050 typ.			
K1	0.56	-	=	0.022	-	=	
Н	0.51	0.61	0.71	0.020	0.024	0.028	
L	0.51	0.61	0.71	0.020	0.024	0.028	
L1	0.06	0.13	0.20	0.002	0.005	0.008	
θ	0°	-	12°	0°	-	12°	
W	0.15	0.25	0.36	0.006	0.010	0.014	
M	0.125 typ.			0.005 typ.			
ECN: C13-0702-Rev. K, 20)-May-13			•			

Revison: 20-May-13 Document Number: 71655



RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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Revision: 02-Oct-12 Document Number: 91000